

Laser Annealing Novel Substrates for Rutile Thin Films

Monique J. Kubovsky¹, Yorick A. Birkholzer², Darrell G. Schlom^{2,3,4}

¹ Department of Physics, University of Florida, Gainesville, FL USA.

² Department of Materials Science and Engineering, Cornell University, Ithaca, NY USA.

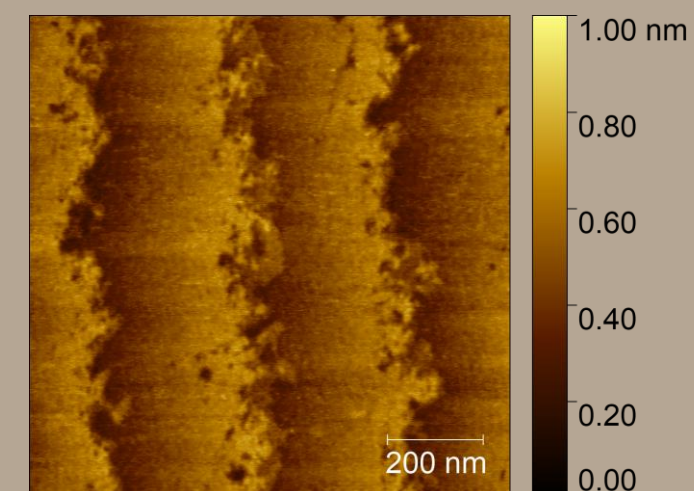
³ Kavli Institute for Nanoscale Science, Cornell University, Ithaca, NY USA.

⁴ Leibniz-Institut für Kristallzüchtung, Berlin, Germany.

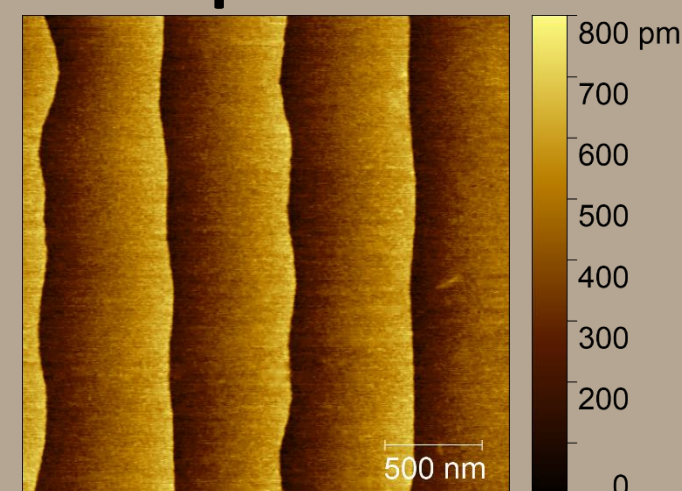
Introduction

- Superconductivity discovered in epitaxially strained RuO_2 thin films [1]
- Possibility for other rutile thin films to superconduct
- Need a set of optimally prepared substrates

As-received

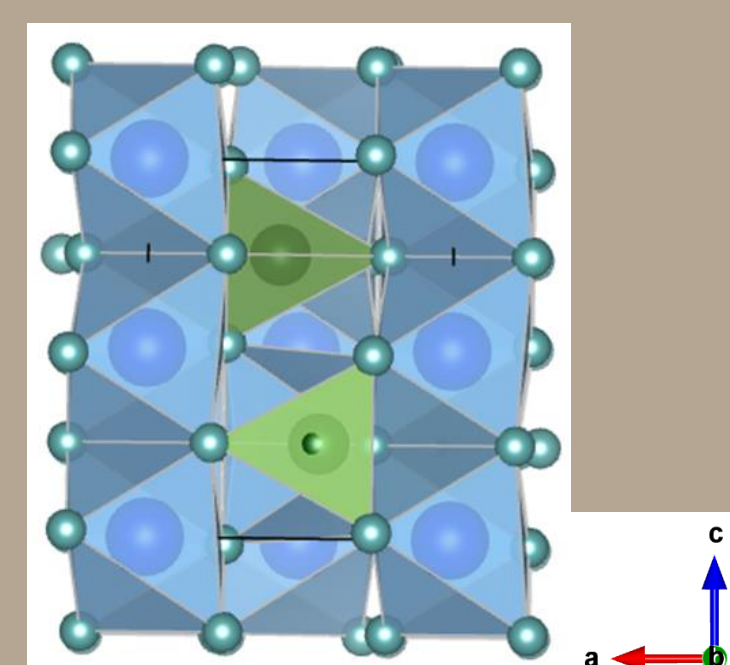
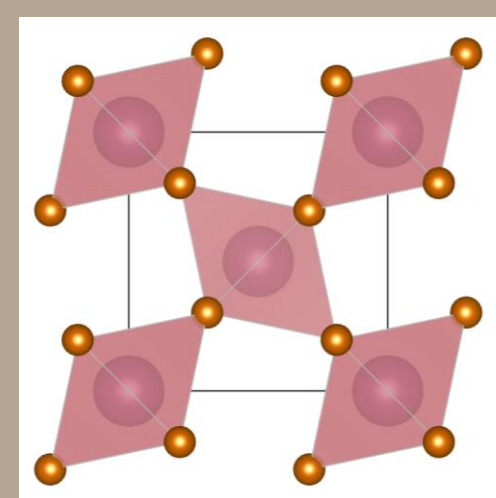


Prepared

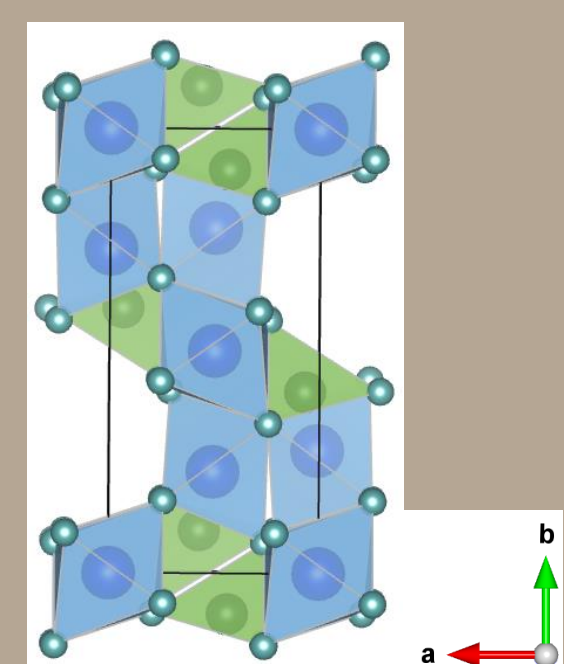


Treatments

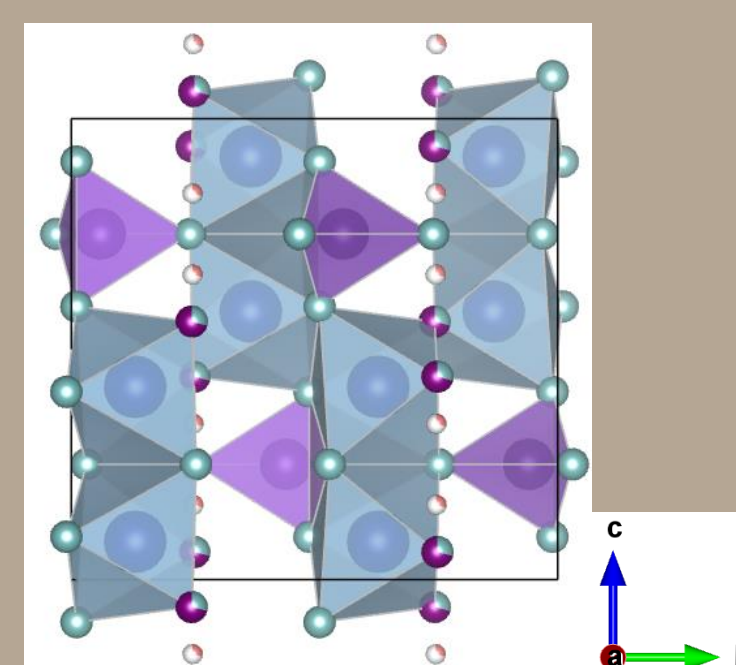
- Desired criteria:
 - Stable under oxidizing and reducing conditions at high temperatures
 - Rutile-like crystal structure
 - Oxide with octahedral coordination



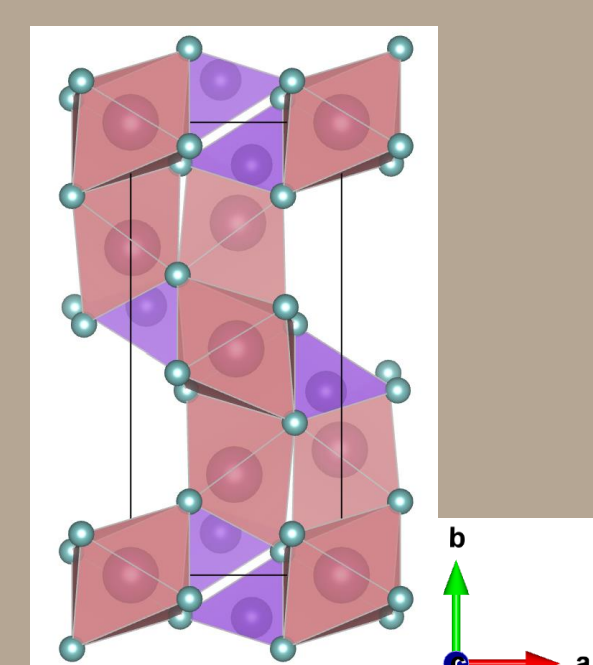
(001) BeAl_2O_4



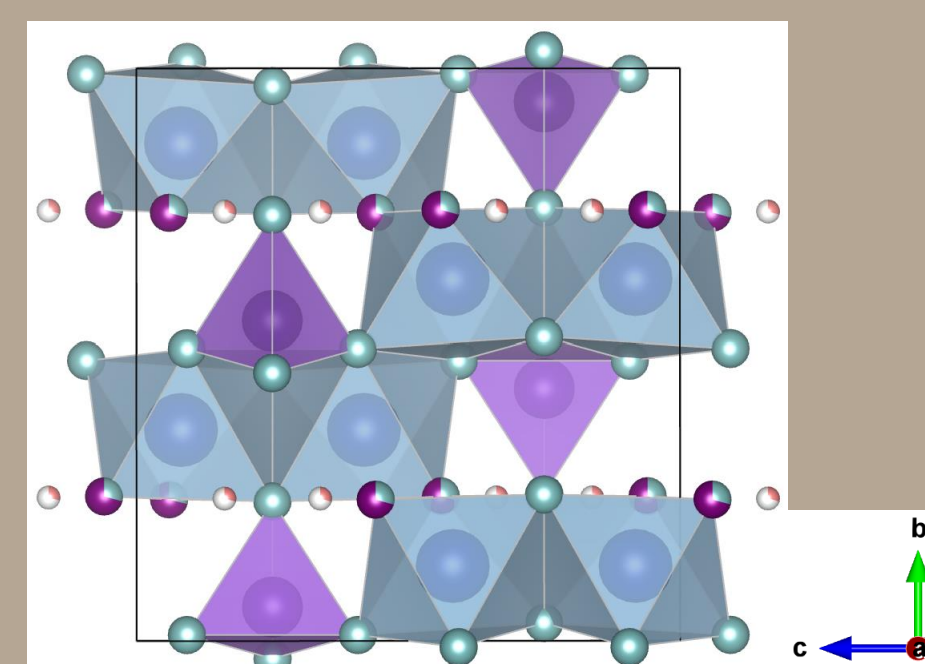
(010) BeAl_2O_4



(001) Topaz



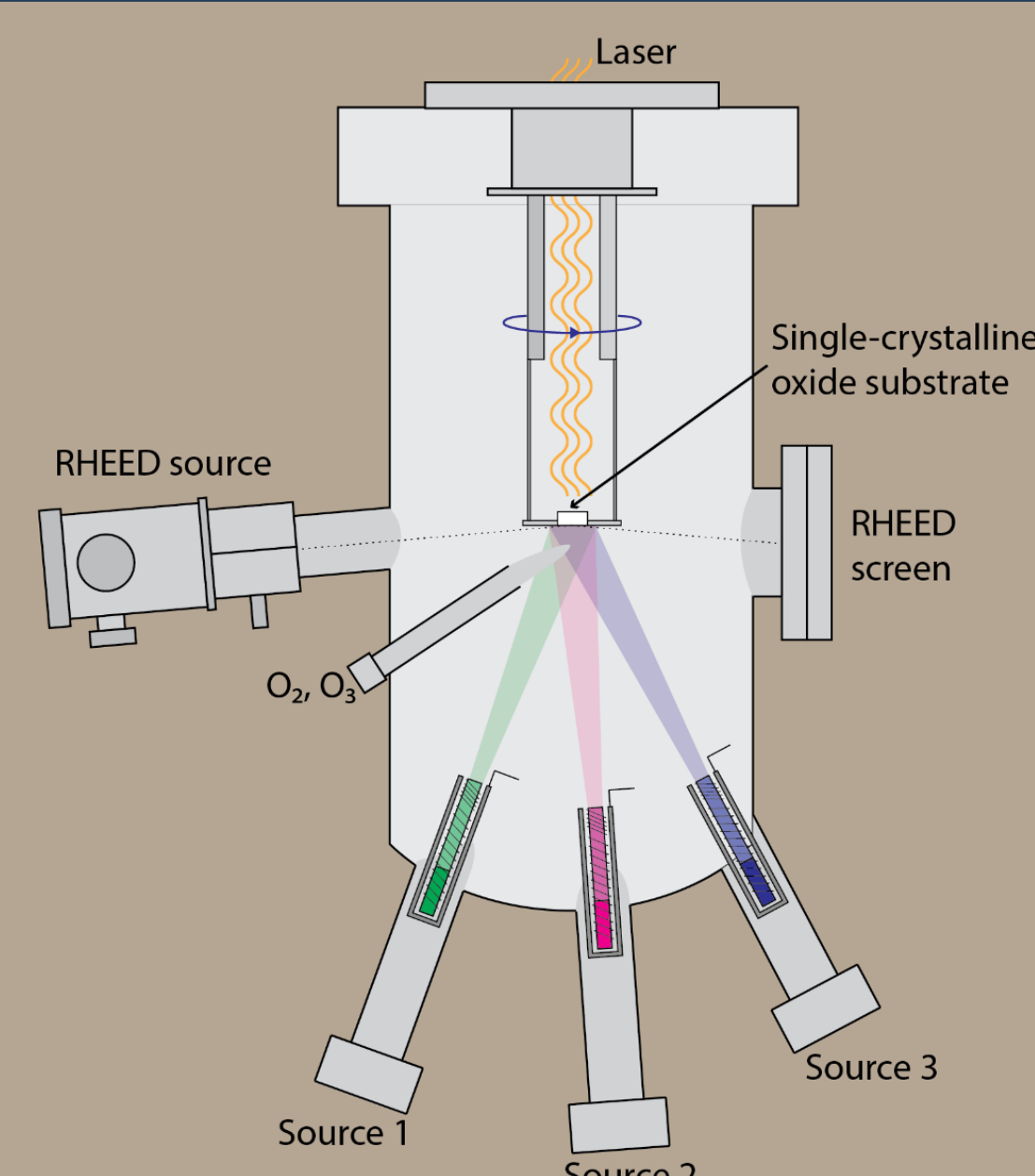
(010) Mg_2SiO_4



(010) Topaz

Methods

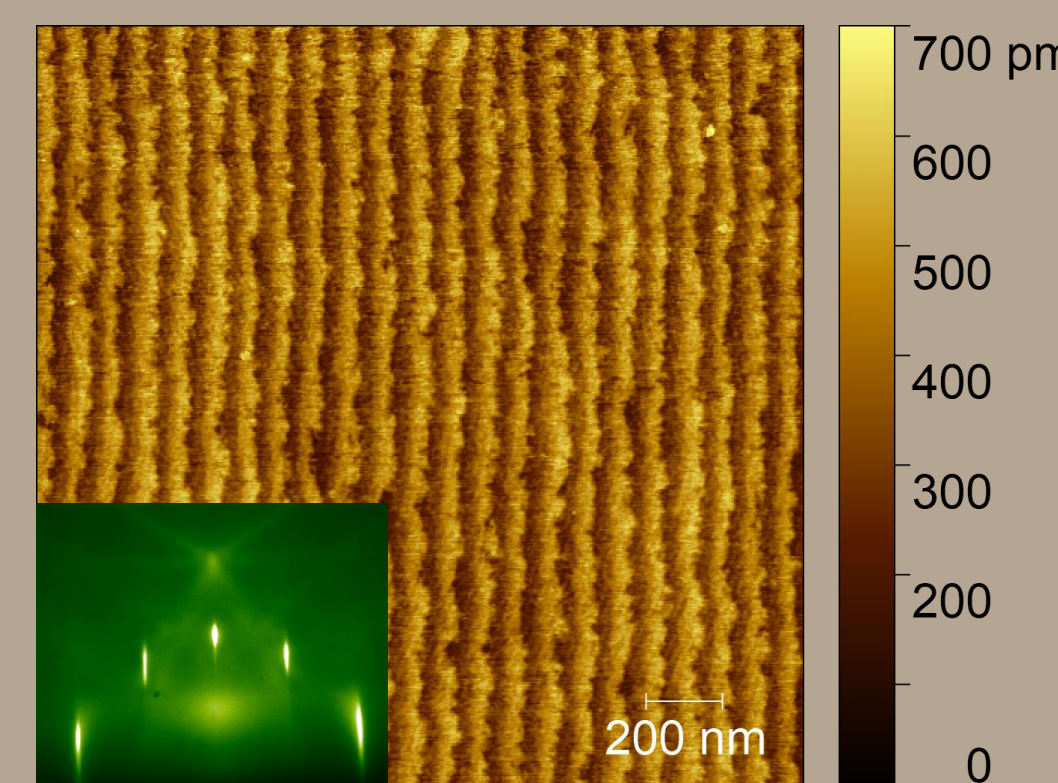
- Laser annealing
- Furnace annealing
- HF acid etching
- Atomic force microscopy



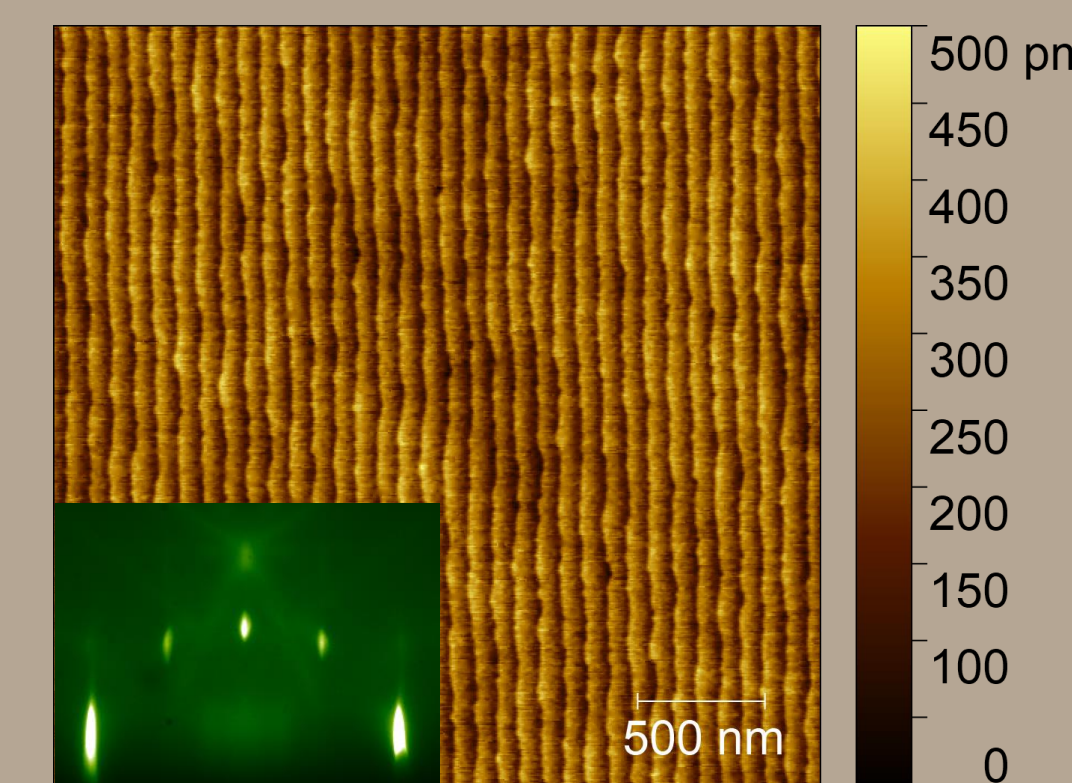
Results

- Laser annealing (001) BeAl_2O_4 :

As-received

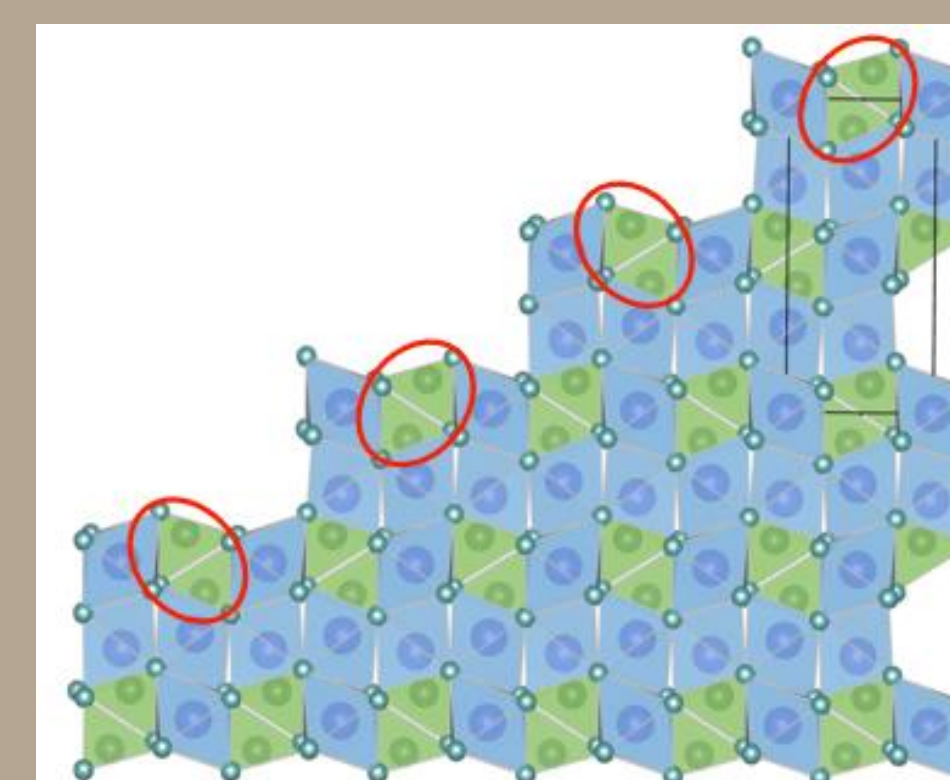


1250 °C 200 s

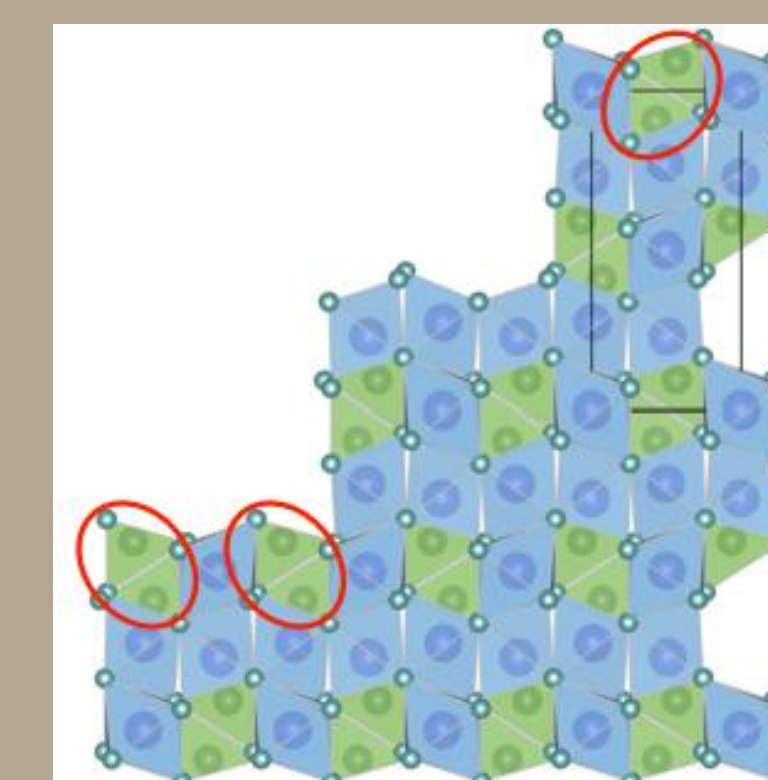


- Laser annealing (010) BeAl_2O_4 :

- Double termination



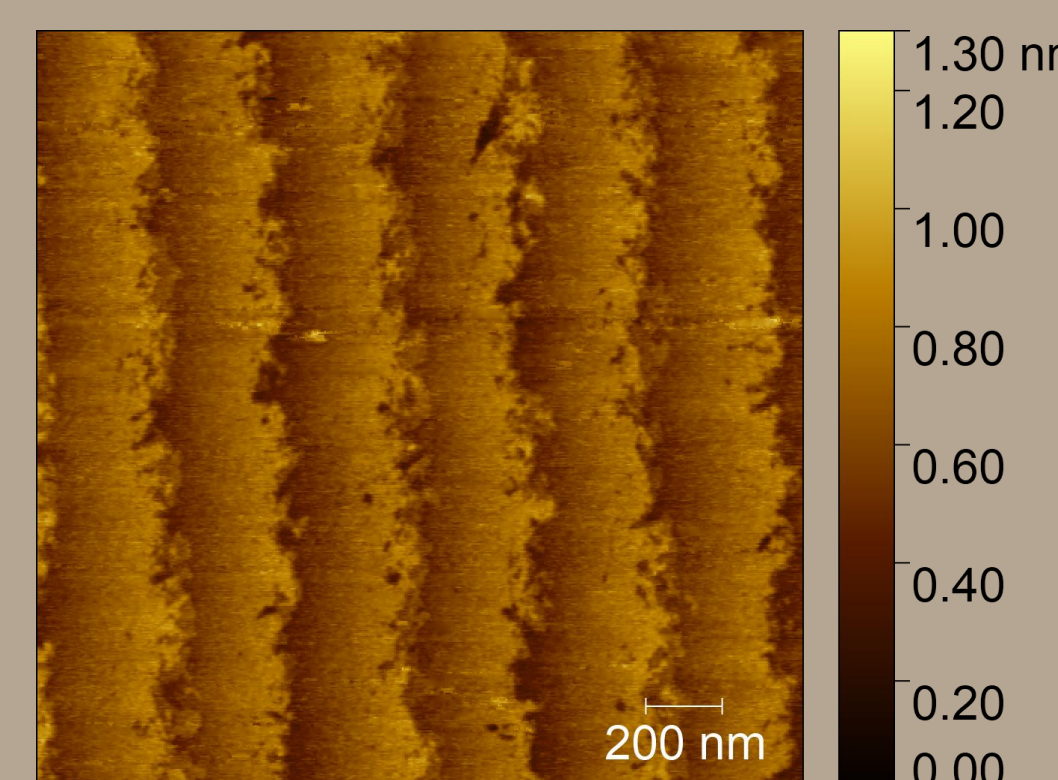
~2/5 unit cell step height (0.37 nm)



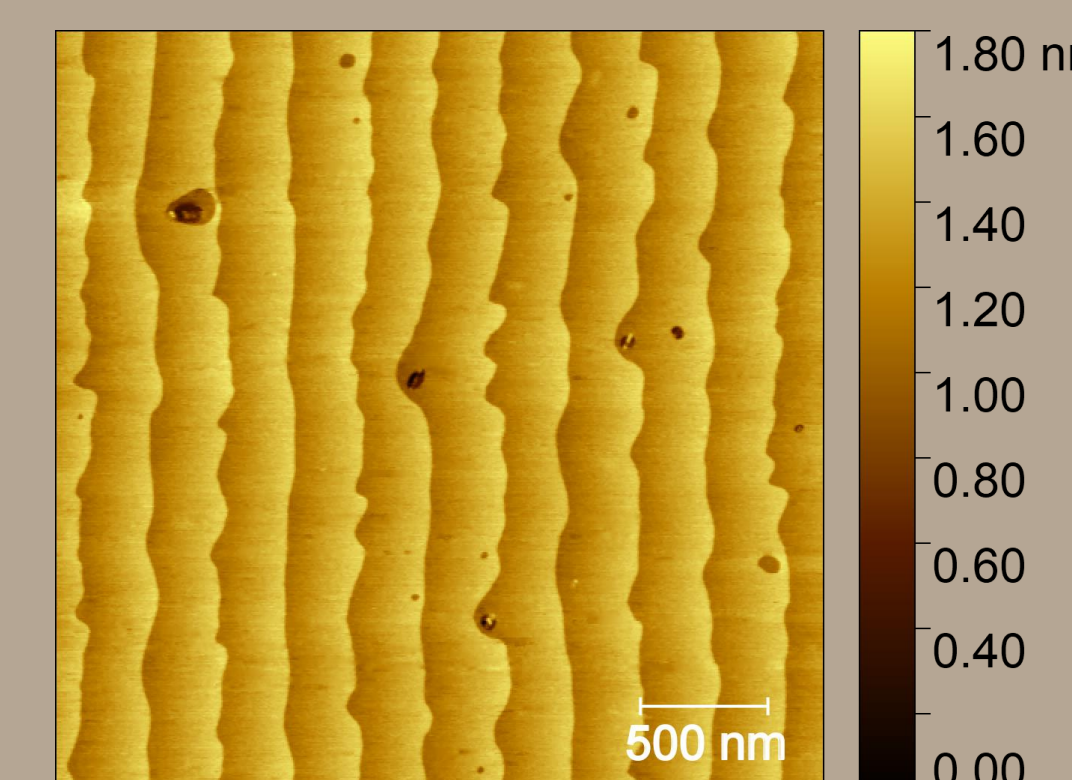
~3/5 unit cell step height (0.56 nm)

- Furnace annealing (010) BeAl_2O_4 :

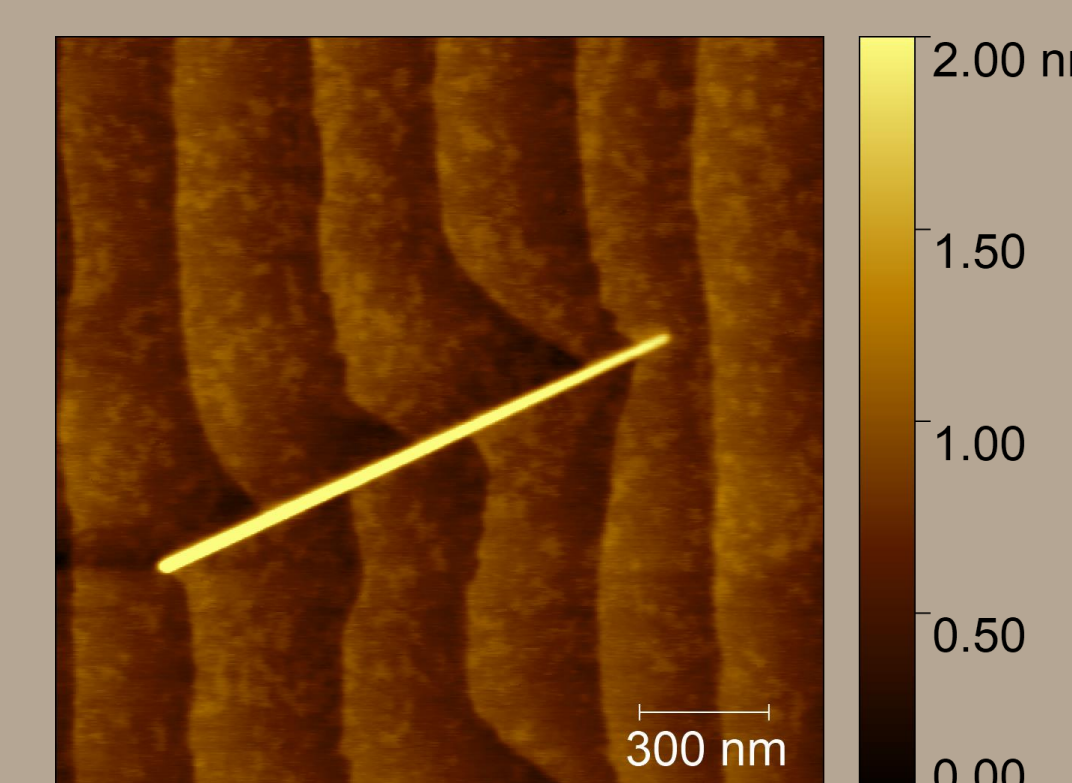
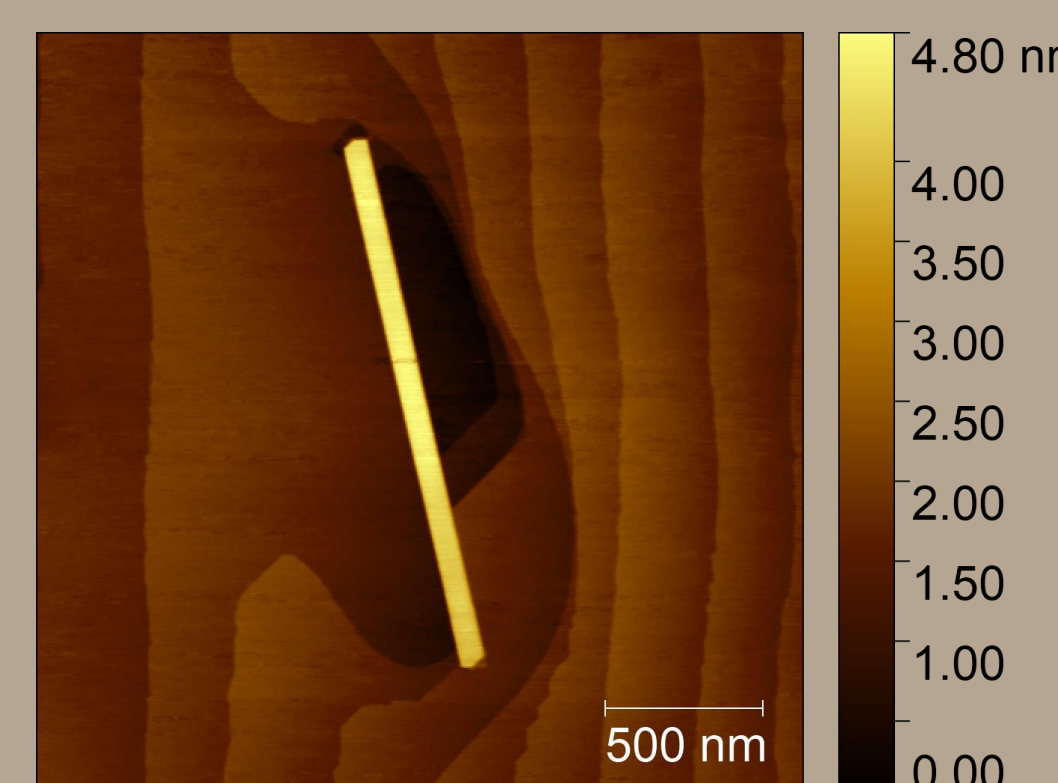
As-received



900 °C 1 hr

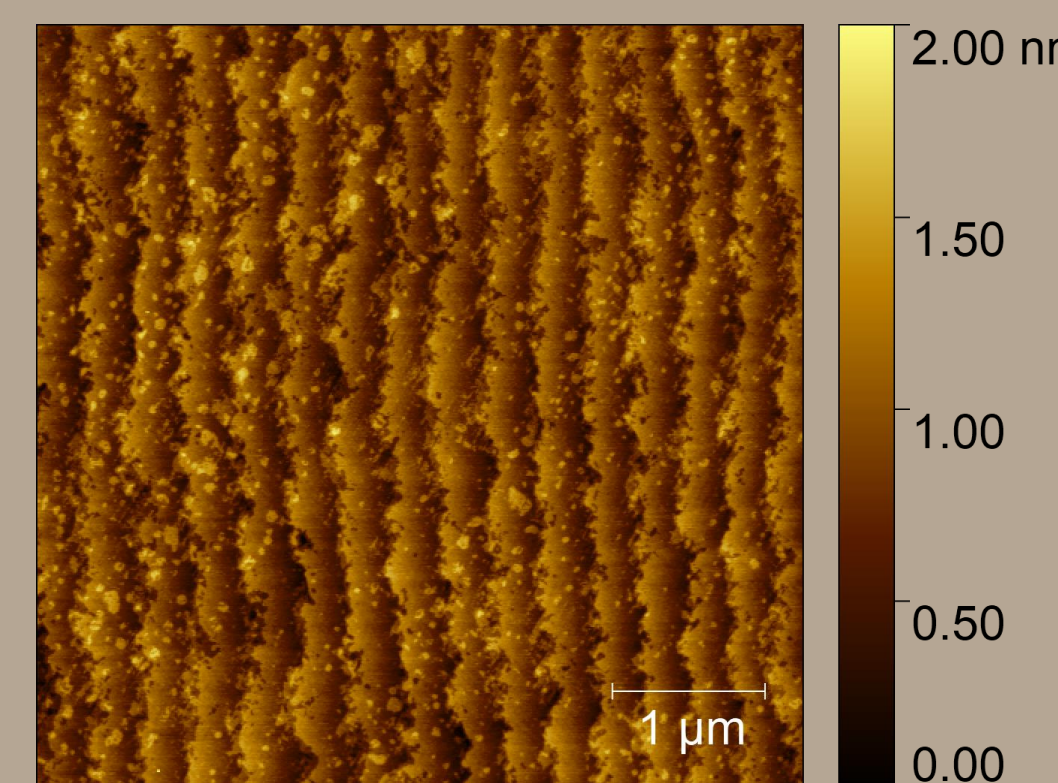


- Needle defects

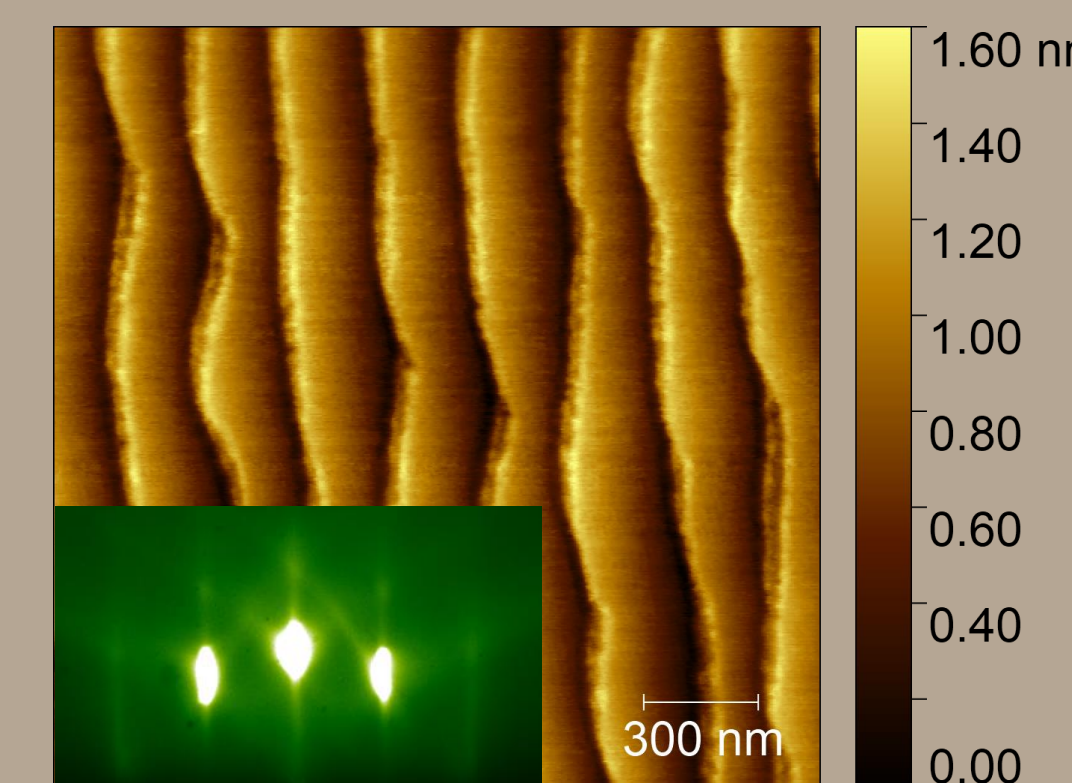


- Laser annealing (010) Mg_2SiO_4 :

As-received



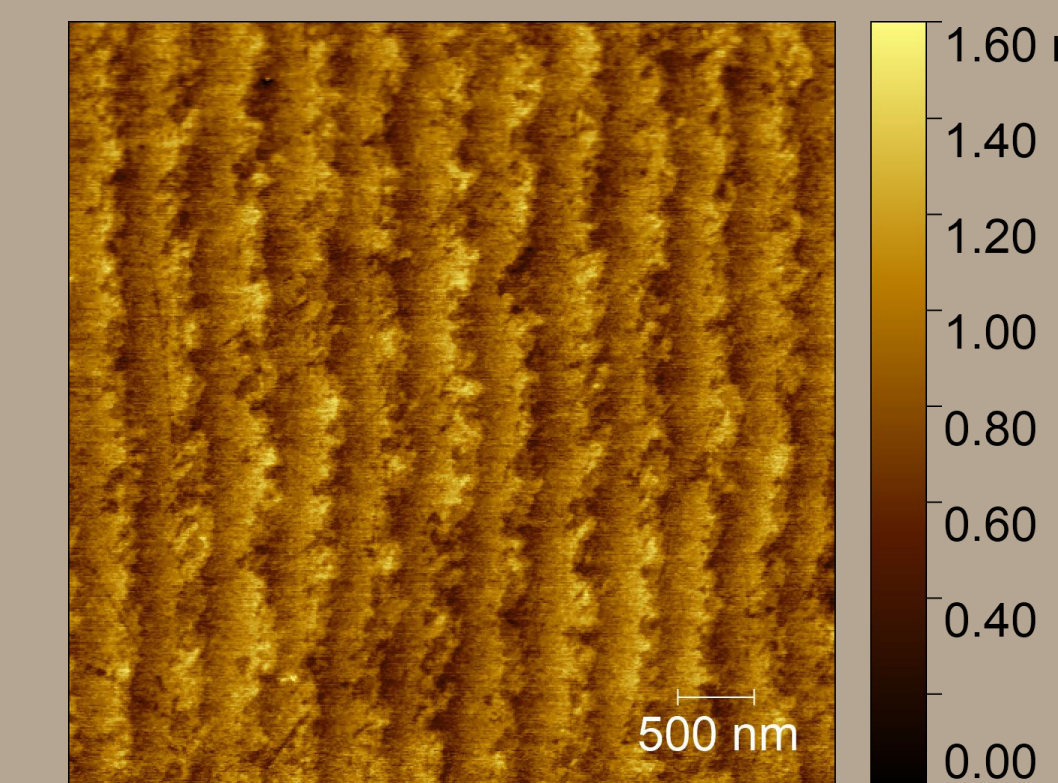
1300 °C 200 s



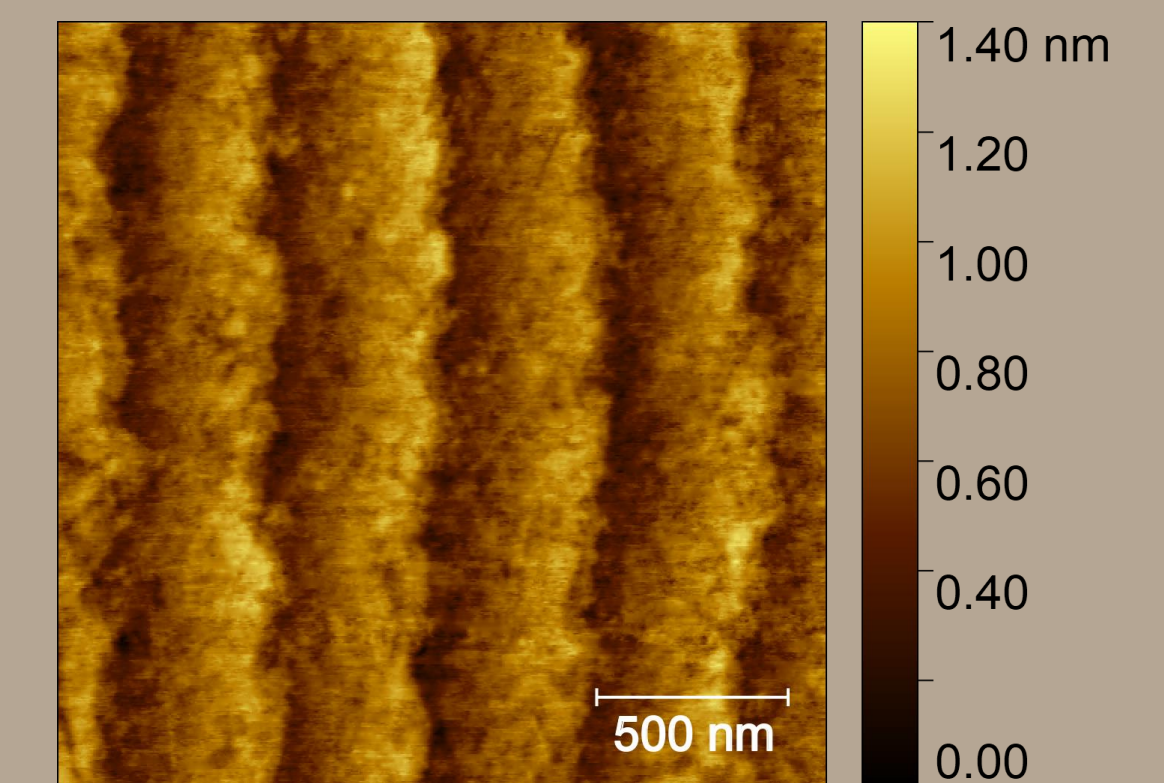
Results (Continued)

- Furnace annealing (001) topaz:

As-received

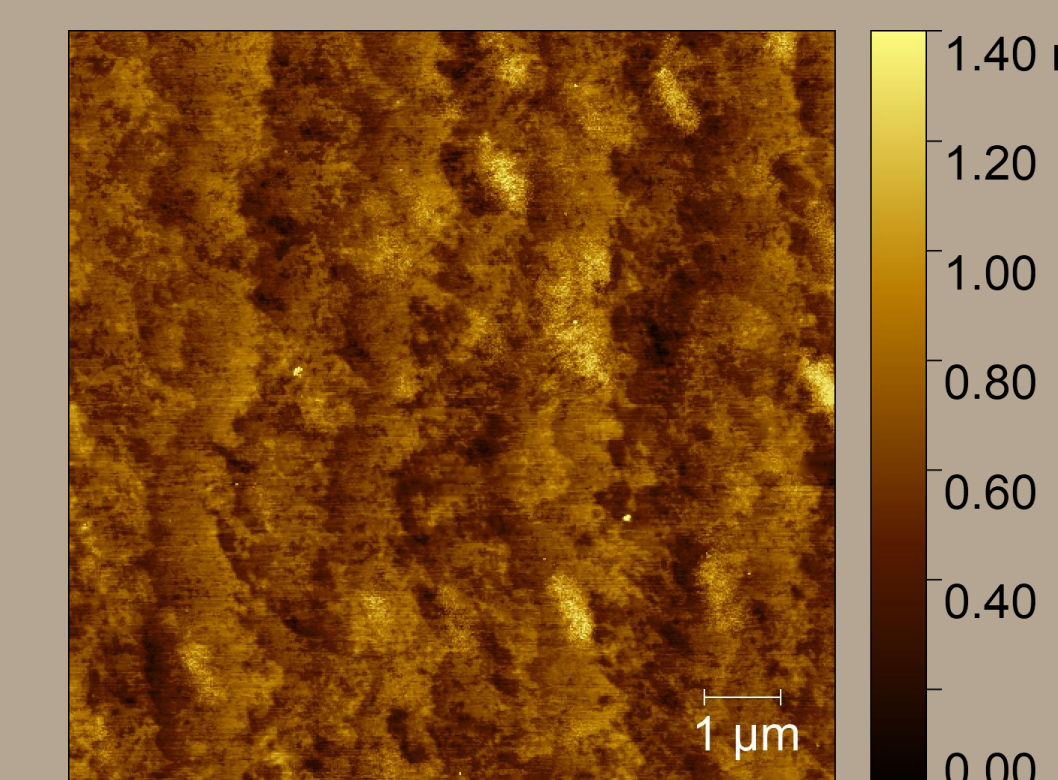


750 °C 1 hr

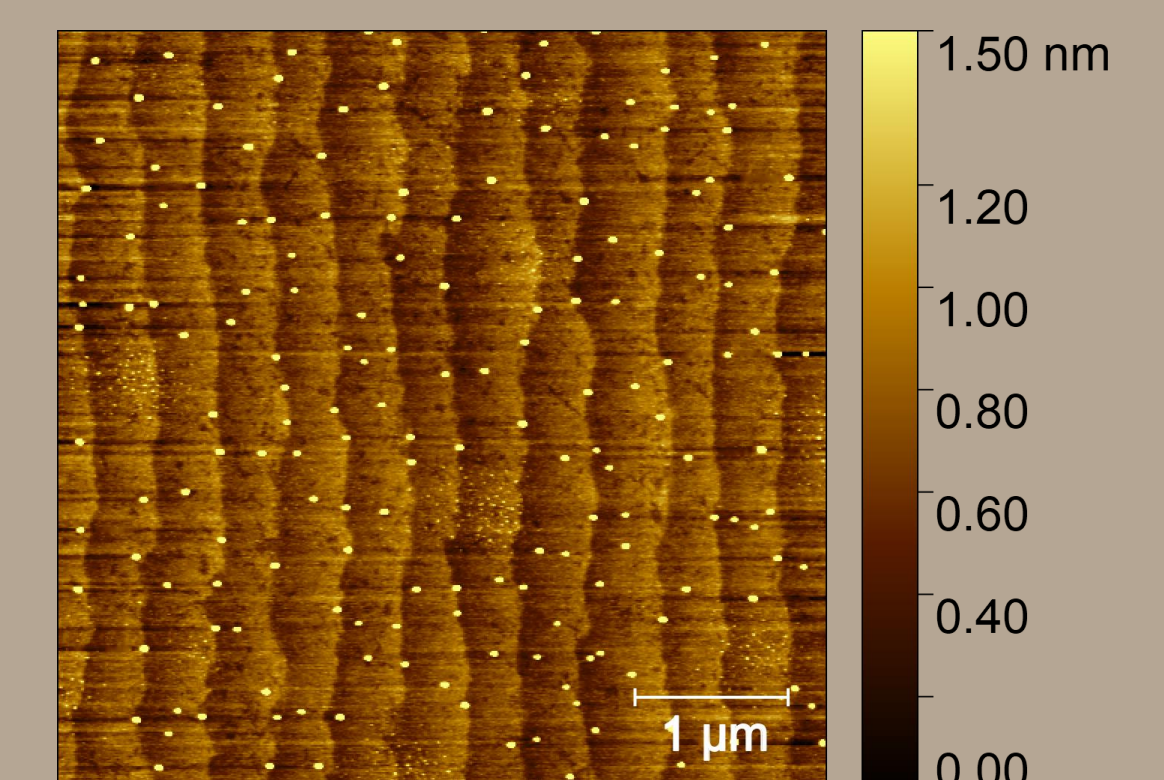


- Furnace annealing (010) topaz:

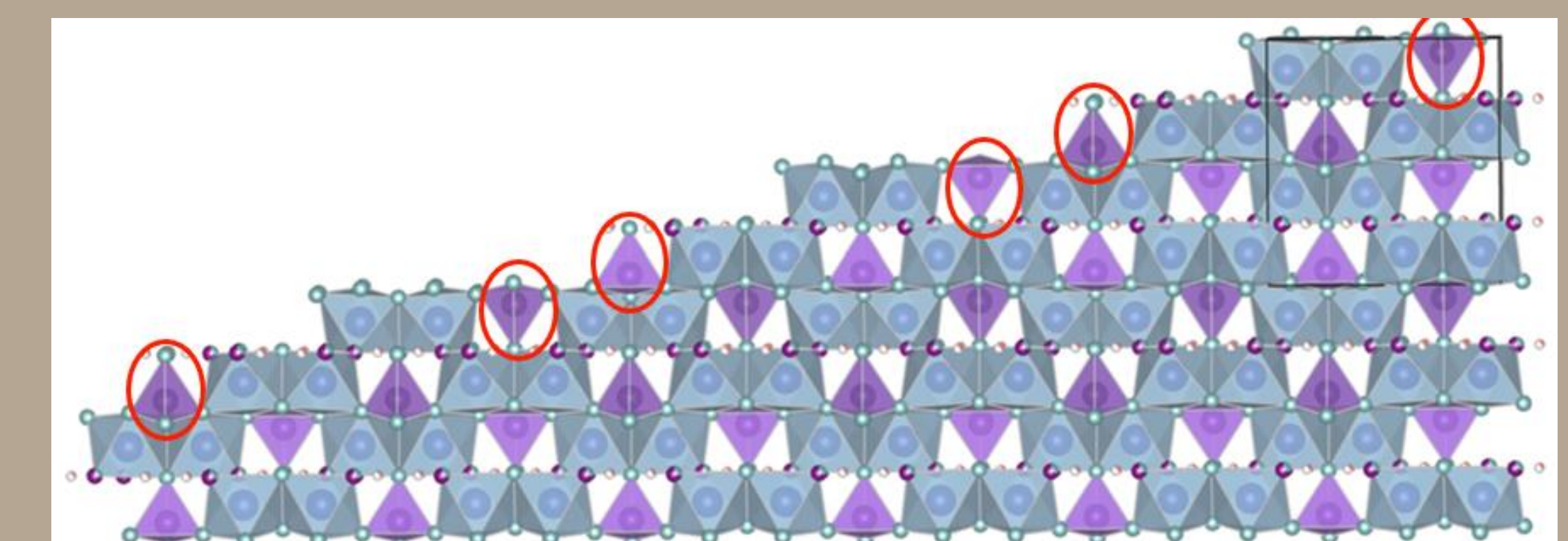
As-received



600 °C 1 hr



- Double termination



~1/4 unit cell step height (0.22 nm)

Conclusions

Successfully developed processes that prepare these substrates for thin film deposition, accelerating the search for superconducting rutiles

Acknowledgements

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References

¹J.P. Ruf et al., Nat. Commun. 12, (2021), 41467.